NSN 5962-01-283-4317

Digital Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-283-4317

Body Length:

0.405 inches

Body Width:

Between 0.220 inches and 0.310 inches

Body Height:

0.185 inches

Maximum Power Dissipation Rating:

210.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Monolithic and hermetically sealed and high voltage and medium speed

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

Dual 2 input

Design Function And Quantity:

2 gate, or

Case Outline Source And Designator:

D-4 mil-m-38510

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

25.00 nanoseconds propagation delay time, low to high level output and 25.00 nanoseconds propagation delay time, high to low level output

Special Features:

1050 milliwatt continous total dissipation at 25 degrees c

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

8 printed circuit

Specification Data:

81349-mil-m-38510/129 government specification

Shelf Life:

NI/o

NSN 5962-01-283-4317

Digital Microcircuit - Page 2 of 2



		eas	

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0